

## EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L2	0	isulated adj gate with mosfet same power	USPAT	OR	OFF	2006/09/13 19:56
L3	1128	insulated adj gate with mosfet same power	US-PGPUB; USPAT	OR	OFF	2006/09/13 21:05
L4	857	insulated adj gate with mosfet with power	US-PGPUB; USPAT	OR	OFF	2006/09/13 20:00
L5	211	mosfet with power and miller same capacitance	US-PGPUB; USPAT	OR	OFF	2006/09/13 20:36
L7	272	power with mosfet and biasing with resistor	US-PGPUB; USPAT	OR	OFF	2006/09/13 20:37
L8	43	power with mosfet same biasing with resistor	US-PGPUB; USPAT	OR	OFF	2006/09/13 21:19
L9	229	power with mosfet same bias\$ with resistor	US-PGPUB; USPAT	OR	OFF	2006/09/13 20:39
L11	151	power with mosfet and discrete with capacitor	US-PGPUB; USPAT	OR	OFF	2006/09/13 21:05
L12	26	power with mosfet and discrete with capacitor same gate	US-PGPUB; USPAT	OR	OFF	2006/09/13 21:05
L13	229	power with mosfet same bias\$ with resistor	US-PGPUB; USPAT	OR	OFF	2006/09/13 21:19
S1	13595	(igfet insulated adj gate)	USPAT	OR	OFF	2006/09/13 16:10
S2	718	(igfet insulated adj gate) and (capacitance same ratio miller with plateau)	USPAT	OR	OFF	2006/09/13 16:11
S3	558	(igfet insulated adj gate) and (capacitance same ratio miller with plateau) and power	USPAT	OR	OFF	2006/09/13 16:12
S4	734	(igfet insulated adj gate) and (capacitance same ratio miller with plateau) and power	US-PGPUB; USPAT	OR	OFF	2006/09/13 16:13
S5	460	(igfet insulated adj gate) and (capacitance with ratio miller with plateau) and power	US-PGPUB; USPAT	OR	OFF	2006/09/13 16:14
S6	24	(igfet insulated adj gate) and (miller with plateau) and power	US-PGPUB; USPAT	OR	OFF	2006/09/13 16:13
S7	0	(igfet insulated adj gate) and (capacitance with ratio and miller with plateau) and power	US-PGPUB; USPAT	OR	OFF	2006/09/13 16:14
S8	0	(igfet insulated adj gate) and (capacitance same ratio and miller with plateau) and power	US-PGPUB; USPAT	OR	OFF	2006/09/13 16:14

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S9	24	(igfet insulated adj gate) and (capacitance and miller with plateau) and power	US-PGPUB; USPAT	OR	OFF	2006/09/13 16:33
S10	117	(igfet insulated adj gate) and capacitor same (gate electrode ) and (capacitance same miller ) and power	US-PGPUB; USPAT	OR	OFF	2006/09/13 16:45
S11	60	(igfet insulated adj gate) and capacitor same gate same (gate electrode ) and (capacitance same miller ) and power same mosfet	US-PGPUB; USPAT	OR	OFF	2006/09/13 16:52
S12	0	capacitance with off and capacitance with on and power with mosfet and capacitor	US-PGPUB; USPAT	OR	OFF	2006/09/13 16:52
S13	0	capacitance with off and capacitance with on and power with mosfet	US-PGPUB; USPAT	OR	OFF	2006/09/13 16:53
S14	0	capacitance with off and capacitance with on and power same mosfet	US-PGPUB; USPAT	OR	OFF	2006/09/13 16:53
S15	1106	capacitance with off and power same mosfet	US-PGPUB; USPAT	OR	OFF	2006/09/13 16:53
S16	0	capacitance with on and power same mosfet	US-PGPUB; USPAT	OR	OFF	2006/09/13 16:53
S17	1106	capacitance with off and power same mosfet	US-PGPUB; USPAT	OR	OFF	2006/09/13 16:53
S18	858	capacitance with off and power same mosfet and power with mosfet	US-PGPUB; USPAT	OR	OFF	2006/09/13 16:53
S19	48	capacitance with off same ratio and power same mosfet and power with mosfet	US-PGPUB; USPAT	OR	OFF	2006/09/13 17:00
S20	300	discrete same capacitor and power with mosfet	US-PGPUB; USPAT	OR	OFF	2006/09/13 17:00
S21	40	discrete same capacitor and power with mosfet and (igfet insulated adj gate)	US-PGPUB; USPAT	OR	OFF	2006/09/13 17:01